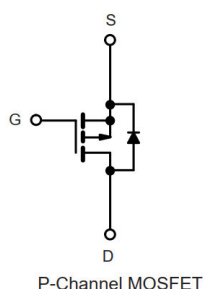
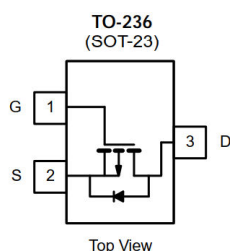


P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$ (Ω)	$V_{GS(th)}$ (V)	I_D (mA)
- 60	5 at $V_{GS} = - 10$ V	- 1 to - 3	- 130



FEATURES

- DT-Trench Power MOSFET
- High-Side Switching
- Low On-Resistance: 5 Ω
- Low Threshold: - 2 V (typ.)
- Fast Switching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- 1200 V ESD Protection
- Compliant to RoHS Directive 2002/95/EC



RoHS
COMPLIANT

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- Battery Operated Systems
- Power Supply Converter Circuits
- Solid-State Relays

BENEFITS

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Easily Driven without Buffer

ABSOLUTE MAXIMUM RATINGS $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	- 60	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^a	I_D	- 130	mA
	I_D	- 105	
Pulsed Drain Current ^b	I_{DM}	- 800	
Power Dissipation ^a	P_D	350	mW
	P_D	140	
Maximum Junction-to-Ambient ^a	R_{thJA}	350	$^{\circ}\text{C/W}$
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	$^{\circ}\text{C}$

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.

SPECIFICATIONS $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted						
Parameter	Symbol	Test Conditions	Limits			Unit
			Min.	Typ. ^a	Max.	
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}$, $I_D = -10\text{ }\mu\text{A}$	- 60			V
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$	- 1		- 3	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$			± 10	μA
		$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 10\text{ V}$			± 200	nA
		$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 10\text{ V}$, $T_J = 85\text{ }^{\circ}\text{C}$			± 500	
		$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 5\text{ V}$			± 100	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$			- 25	
		$V_{DS} = -60\text{ V}$, $V_{GS} = 0\text{ V}$, $T_J = 85\text{ }^{\circ}\text{C}$			- 250	
On-State Drain Current ^a	$I_{D(on)}$	$V_{GS} = -10\text{ V}$, $V_{DS} = -4.5\text{ V}$	- 50			mA
		$V_{GS} = -10\text{ V}$, $V_{DS} = -10\text{ V}$	- 600			
Drain-Source On-Resistance ^a	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}$, $I_D = -25\text{ mA}$			10	Ω
		$V_{GS} = -10\text{ V}$, $I_D = -500\text{ mA}$			5	
		$V_{GS} = -10\text{ V}$, $I_D = -500\text{ mA}$, $T_J = 125\text{ }^{\circ}\text{C}$			9	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -10\text{ V}$, $I_D = -100\text{ mA}$	80			mS
Diode Forward Voltage	V_{SD}	$I_S = -200\text{ mA}$, $V_{GS} = 0\text{ V}$			- 1.4	V
Dynamic						
Total Gate Charge	Q_g	$V_{DS} = -30\text{ V}$, $V_{GS} = -15\text{ V}$ $I_D \cong -500\text{ mA}$		1.7		nC
Gate-Source Charge	Q_{gs}			0.26		
Gate-Drain Charge	Q_{gd}			0.46		
Input Capacitance	C_{iss}	$V_{DS} = -25\text{ V}$, $V_{GS} = 0\text{ V}$ $f = 1\text{ MHz}$		37		pF
Output Capacitance	C_{oss}			5		
Reverse Transfer Capacitance	C_{rss}			2.3		
Switching ^b						
Turn-On Time	$t_{d(on)}$	$V_{DD} = -25\text{ V}$, $R_L = 150\text{ }\Omega$ $I_D \cong -200\text{ mA}$, $V_{GEN} = -10\text{ V}$, $R_g = 10\text{ }\Omega$		20		ns
Turn-Off Time	$t_{d(off)}$			35		

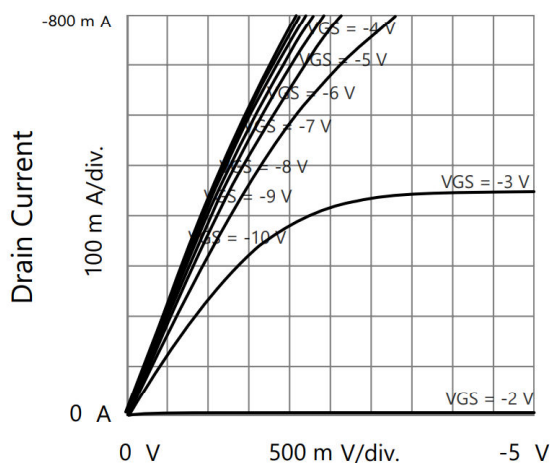
Notes:

 a. Pulse test: $PW \leq 300\text{ }\mu\text{s}$ duty cycle $\leq 2\%$.

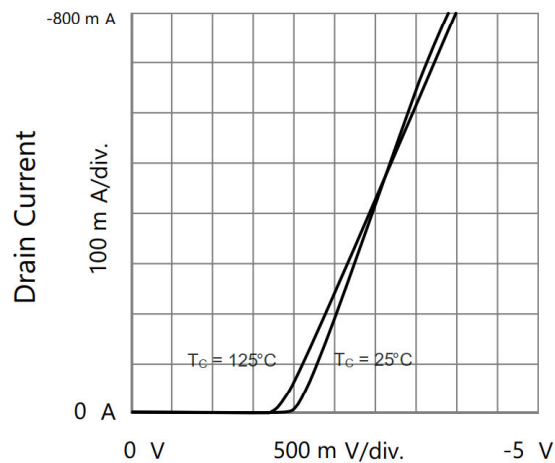
b. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

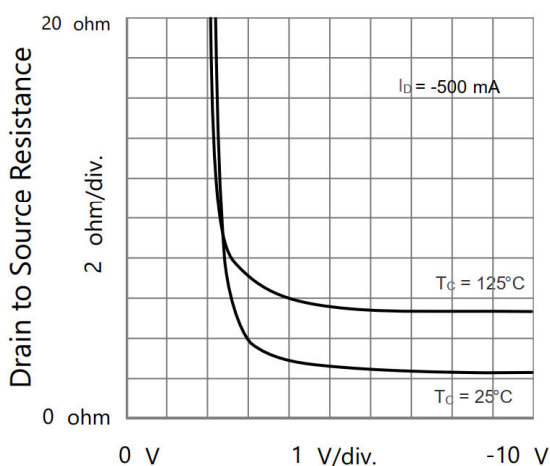
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



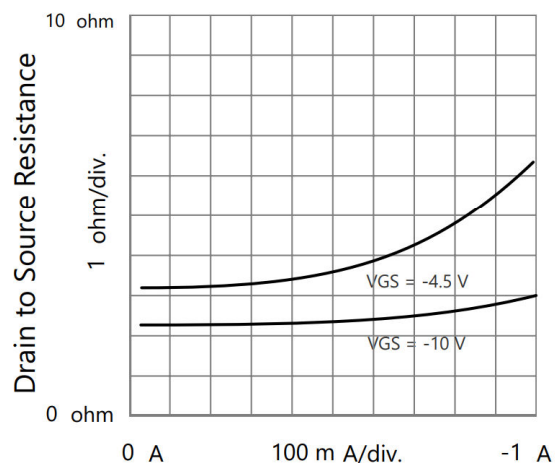
Drain to Source Voltage
Output Characteristics



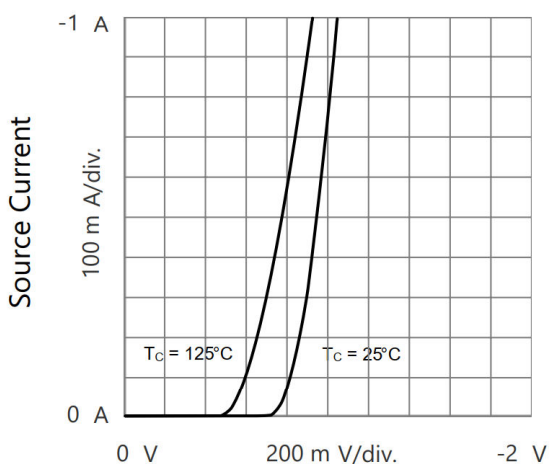
Gate to Source Voltage
Transfer Characteristics



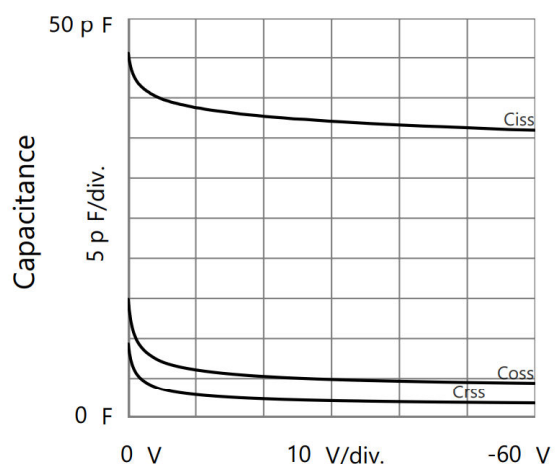
Gate to Source Voltage
Drain to Source Resistance vs. Gate to Source Voltage



Drain Current
Drain to Source Resistance vs. Drain Current

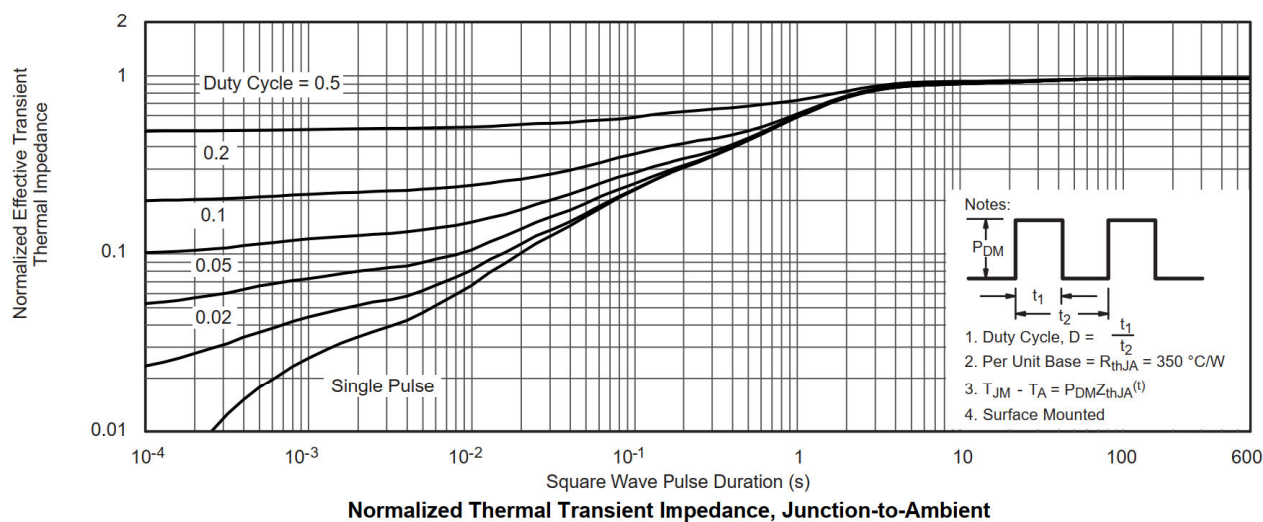
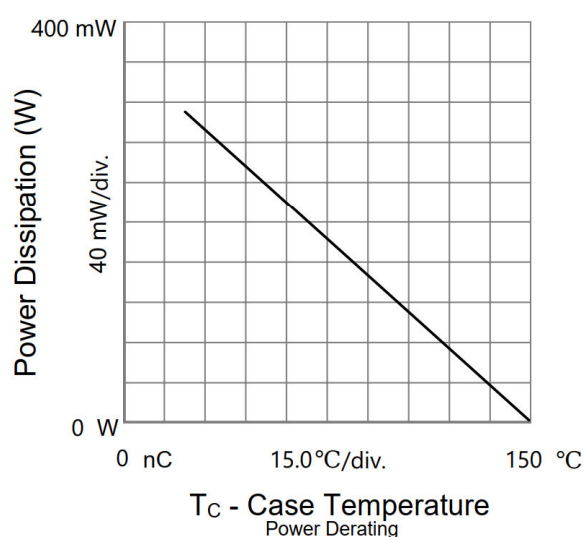
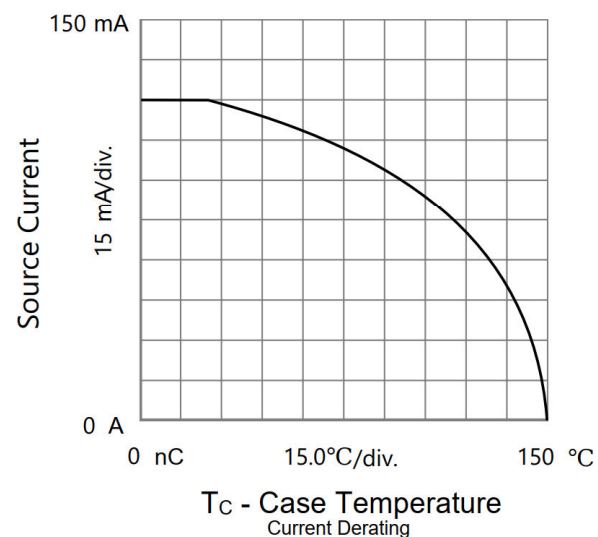
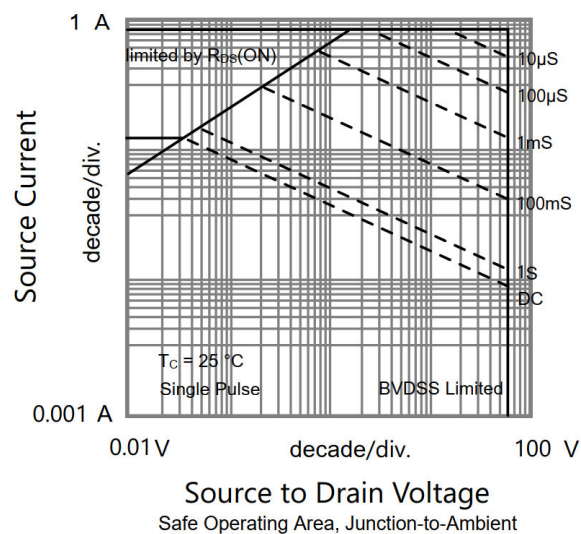
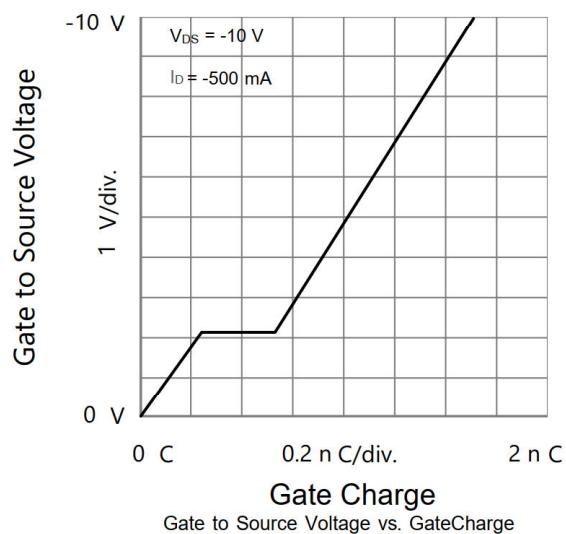


Source to Drain Voltage
Body Diode Forward Characteristics



Drain to Source Voltage
Capacitances

THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



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